



The PA-2 series of conductive cooled polygonal diode laser array is a high peak power product developed by RealLight for use at high temperatures of 60°C. The PA-2 series is composed of twelve hexagonally arranged stacks, with 1 ~ 4 bars in each stack, and each bar has a power of 100W/200W. Other wavelengths and packaging forms can be customized.

Key Features

- AuSn solder for packaging
- High temperature application
- High peak power
- High reliability

Applications

Pumping source

Illumination

Laser processing

Scientific research

Technical Specifications

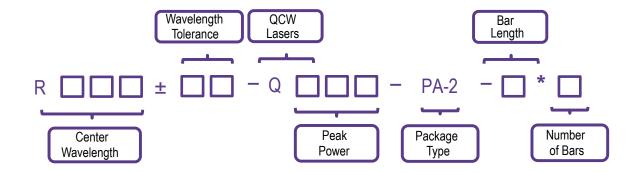
Optical Par	ameters		
Center Wavelength λ _c (nm)	790~812		
Wavelength Tolerance δλ _c (nm)	±3		
Output Power per Bar (W)	100	200	
Number of Horizontal Arrays	2	2	
Array-to-Array Pitch	3		
Number of Bars per Stack	1~4	1~3	
Bar-to-Bar Pitch (mm)	0.43	0.55	
Spectral Width (FWHM) (nm)	≤6		
Fast Axis Divergence Angle (FWHM) (typ., °)	40		
Slow Axis Divergence Angle (FWHM) (typ.,°)	10		
Wavelength Temperature Coefficient(nm/°C)	~0.3		
Electrical Pa	rameters		
EO Conversion Efficiency (%)	≥50		
Threshold Current Ith (A)	≤20	≤30	
Operating Current I _{op} (A)	100	220	
Operating Voltage V _{op} of each Bar(V)	≤2	≤2.1	
Duty Cycle (%)	≤0.8%@4800W	≤0.6%@7200W	
Pulse Width (μs)	≤300		
Repetition Rate (Hz)	≤25	≤20	
Environment F	Parameters		
Operating Temperature (°C)	-40	-40~65	
Storage Temperature(°C)	-45	-45~85	

- 1. Wavelengths from 940nm to 960nm available upon request.
- 2. Custom number of bars, bar-to-bar pitch, and stack-to-stack pitch are available upon request.
- 3. The installation and wiring can be customized to meet the customer's requirements.
- 4. All the data in the above table are the typical values obtained from the tests at room temperature of 25°C, and the final data is subject to the final test report.





Part Numbering Schema



Mechanical Drawings (in mm)

